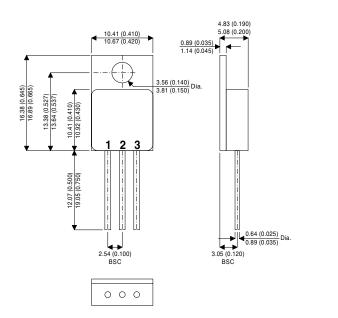
## IRFY140-T257



Pad 1 - Gate

MECHANICAL DATA Dimensions in mm (inches)



TO-257AA - Metal Package

Pad 2 – Drain

## N-CHANNEL POWER MOSFET FOR HI-REL APPLICATIONS

V <sub>DSS</sub>	100V
I <sub>D(cont)</sub>	18A
R <sub>DS(on)</sub>	0.092Ω

#### **FEATURES**

- HERMETICALLY SEALED TO257AA METAL PACKAGE
- SIMPLE DRIVE REQUIREMENTS
- LIGHTWEIGHT
- SCREENING OPTIONS AVAILABLE
- ALL LEADS ISOLATED FROM CASE

#### ABSOLUTE MAXIMUM RATINGS (T<sub>case</sub> = 25°C unless otherwise stated)

Pad 3 - Source

V <sub>GS</sub>	Gate – Source Voltage	±20V		
I <sub>D</sub>	Continuous Drain Current @ T <sub>case</sub> = 25°C	18A		
I <sub>D</sub>	Continuous Drain Current @ T <sub>case</sub> = 100°C 12A			
I <sub>DM</sub>	Pulsed Drain Current	72A		
PD	Power Dissipation @ $T_{case} = 25^{\circ}C$	50W		
	Linear Derating Factor	0.48W/°C		
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Temperature Range	–55 to 150°C		
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case	2.1°C/W max.		
$R_{ hetaJA}$	Thermal Resistance Junction to Ambient	80°C/W max.		

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# **IRFY140-T257**

### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise stated)

	Parameter	Test Cond	litions	Min.	Тур.	Max.	Unit	
	STATIC ELECTRICAL RATINGS	•						
BV <sub>DSS</sub>	Drain – Source Breakdown Voltage	$V_{GS} = 0$	I <sub>D</sub> = 1mA	100			V	
$\Delta BV_{DSS}$	Temperature Coefficient of	Reference to 25°C			0.1			
$\Delta T_{J}$	Breakdown Voltage	l <sub>D</sub> = 1mA			0.1		V/°C	
R <sub>DS(on)</sub>	Static Drain – Source On–State	V <sub>GS</sub> = 10V	I <sub>D</sub> = 12A			0.092	Ω	
	Resistance	V <sub>GS</sub> = 10V	I <sub>D</sub> = 18A			0.11	52	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$	I <sub>D</sub> = 250μA	2		4	V	
9 <sub>fs</sub>	Forward Transconductance	$V_{DS} \ge 15V$	I <sub>DS</sub> = 12A	9.1			2(Ω)	
1	Zero Gate Voltage Drain Current	$V_{GS} = 0$	$V_{DS} = 0.8BV_{DSS}$			25	- μΑ	
IDSS			T <sub>J</sub> = 125°C			250		
I <sub>GSS</sub>	Forward Gate – Source Leakage	V <sub>GS</sub> = 20V				100		
I <sub>GSS</sub>	Reverse Gate – Source Leakage	$V_{GS} = -20V$				-100	nA	
	DYNAMIC CHARACTERISTICS	•						
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0$			1660			
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 25V		550		pF		
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1MHz			120			
Qg	Total Gate Charge	V <sub>GS</sub> = 10V	I <sub>D</sub> = 18A	20		50		
		$V_{DS} = 0.5BV_{DS}$	SS	30		59	nC	
Q <sub>gs</sub>	Gate – Source Charge	I <sub>D</sub> = 18A	I <sub>D</sub> = 18A			12	nC	
Q <sub>gd</sub>	Gate – Drain ("Miller") Charge	$V_{DS} = 0.5BV_{DSS}$		12		30.7		
t <sub>d(on)</sub>	Turn–On Delay Time				21	ns		
t <sub>r</sub>	Rise Time	$V_{DD} = 50V$ $I_{D} = 18A$ $R_{G} = 9.1\Omega$					145	
t <sub>d(off)</sub>	Turn–Off Delay Time						64	
t <sub>f</sub>	Fall Time						105	
	SOURCE – DRAIN DIODE CHARAC	TERISTICS						
I <sub>S</sub>	Continuous Source Current					18		
I <sub>SM</sub>	Pulse Source Current					73	A	
V <sub>SD</sub>	Diode Forward Voltage	I <sub>S</sub> = 18A	$T_J = 25^{\circ}C$			1 5	v	
		$V_{GS} = 0$				1.5	V I	
t <sub>rr</sub>	Reverse Recovery Time	I <sub>S</sub> = 18A	$T_J = 25^{\circ}C$			400	ns	
Q <sub>rr</sub>	Reverse Recovery Charge	$d_i / d_t \le 100 $ A/µ	ιs V <sub>DD</sub> ≤50V			2.4	μC	
	PACKAGE CHARACTERISTICS	•						
L <sub>D</sub>	Internal Drain Inductance (f	rom 6mm down drain		8.7		n L		
L <sub>S</sub>	Internal Source Inductance (from 6mm down source lead to centre of source bond pad)				8.7		– nH	

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